

## Product Summary

$BV_{DSS}$	$R_{DS(ON)}$	$I_D$ $T_C = +25^\circ C$
-40V	45m $\Omega$ @ $V_{GS} = -10V$	-20A
	55m $\Omega$ @ $V_{GS} = -4.5V$	-18A

## Description

This MOSFET has been designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## Applications

- Backlighting
- DC-DC Converters
- Power Management Functions

## Features

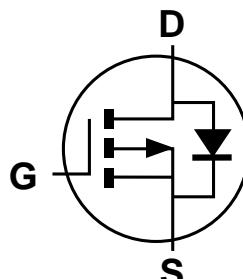
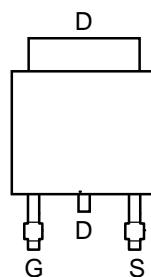
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- Fast Switching Speed
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

## Mechanical Data

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.33 grams (Approximate)



Top View



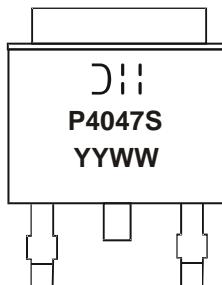
## Ordering Information (Note 4)

Product	Case	Packaging
DMP4047SK3-13	TO252 (DPAK)	2,500/Tape & Reel

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information



III = Manufacturer's Marking  
 P4047S = Product Type Marking Code  
 YYWW = Date Code Marking  
 YY = Year (ex: 17 = 2017)  
 WW = Week (01 to 53)

**Maximum Ratings** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			$V_{DSS}$	-40	V
Gate-Source Voltage			$V_{GSS}$	$\pm 20$	V
Continuous Drain Current (Note 6) $V_{GS} = -10\text{V}$	Steady State	$T_C = +25^\circ\text{C}$ $T_C = +100^\circ\text{C}$	$I_D$	-20 -12.7	A
Maximum Body Diode Continuous Current			$I_S$	-2.5	A
Pulsed Drain Current (10 $\mu\text{s}$ Pulse, Duty Cycle = 1%)			$I_{DM}$	-40	A
Avalanche Current (Note 7) $L = 0.1\text{mH}$			$I_{AS}$	-18	A
Avalanche Energy (Note 7) $L = 0.1\text{mH}$			$E_{AS}$	16	$\text{mJ}$

**Thermal Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^\circ\text{C}$	$P_D$	1.6	W
	$T_A = +70^\circ\text{C}$		1.0	
Thermal Resistance, Junction to Ambient (Note 5)	Steady state	$R_{\theta JA}$	77	$^\circ\text{C}/\text{W}$
	$t < 10\text{s}$		34	
Total Power Dissipation (Note 6)	$T_A = +25^\circ\text{C}$	$P_D$	2.7	W
	$T_A = +70^\circ\text{C}$		1.7	
Thermal Resistance, Junction to Ambient (Note 6)	Steady state	$R_{\theta JA}$	47	$^\circ\text{C}/\text{W}$
	$t < 10\text{s}$		30	
Thermal Resistance, Junction to Case (Note 6)		$R_{\theta JC}$	4.8	
Operating and Storage Temperature Range		$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

**Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b> (Note 8)						
Drain-Source Breakdown Voltage	$BV_{DSS}$	-40	—	—	V	$V_{GS} = 0\text{V}, I_D = -250\mu\text{A}$
Zero Gate Voltage Drain Current $T_J = +25^\circ\text{C}$	$I_{DSS}$	—	—	-1	$\mu\text{A}$	$V_{DS} = -40\text{V}, V_{GS} = 0\text{V}$
Gate-Source Leakage	$I_{GSS}$	—	—	$\pm 100$	nA	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$
<b>ON CHARACTERISTICS</b> (Note 8)						
Gate Threshold Voltage	$V_{GS(\text{TH})}$	-1.0	—	-3.0	V	$V_{DS} = V_{GS}, I_D = -250\mu\text{A}$
Static Drain-Source On-Resistance	$R_{DS(\text{ON})}$	—	33	45	$\text{m}\Omega$	$V_{GS} = -10\text{V}, I_D = -4.4\text{A}$
			40	55		$V_{GS} = -4.5\text{V}, I_D = -3.7\text{A}$
Diode Forward Voltage	$V_{SD}$	—	-0.75	-1.2	V	$V_{GS} = 0\text{V}, I_S = -3.9\text{A}$
<b>DYNAMIC CHARACTERISTICS</b> (Note 9)						
Input Capacitance	$C_{iss}$	—	1328	—	pF	$V_{DS} = -20\text{V}, V_{GS} = 0\text{V}, f = 1.0\text{MHz}$
Output Capacitance	$C_{oss}$	—	103	—	pF	
Reverse Transfer Capacitance	$C_{rss}$	—	81	—	pF	
Gate Resistance	$R_G$	—	7.7	—	$\Omega$	
Total Gate Charge ( $V_{GS} = -4.5\text{V}$ )	$Q_g$	—	11.2	—	nC	$V_{DS} = -20\text{V}, I_D = -4.9\text{A}$
Total Gate Charge ( $V_{GS} = -10\text{V}$ )	$Q_g$	—	23.2	—	nC	
Gate-Source Charge	$Q_{gs}$	—	3.3	—	nC	
Gate-Drain Charge	$Q_{gd}$	—	3.9	—	nC	
Turn-On Delay Time	$t_{D(\text{ON})}$	—	18.5	—	ns	$V_{DS} = -20\text{V}, I_D = -3.9\text{A}$ $V_{GS} = -4.5\text{V}, R_G = 1\Omega$
Turn-On Rise Time	$t_R$	—	28.2	—	ns	
Turn-Off Delay Time	$t_{D(\text{OFF})}$	—	38.8	—	ns	
Turn-Off Fall Time	$t_F$	—	28.6	—	ns	
Body Diode Reverse Recovery Time	$t_{RR}$	—	15.4	—	ns	$I_F = -3.9\text{A}, \text{di}/\text{dt} = 100\text{A}/\mu\text{s}$
Body Diode Reverse Recovery Charge	$Q_{RR}$	—	5.4	—	nC	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

7.  $I_{AS}$  and  $E_{AS}$  ratings are based on low frequency and duty cycles to keep  $T_J = +25^\circ\text{C}$ .

8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.

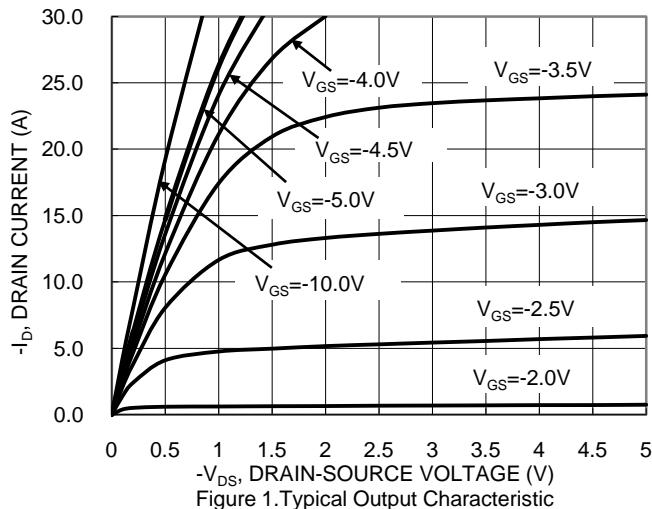


Figure 1. Typical Output Characteristic

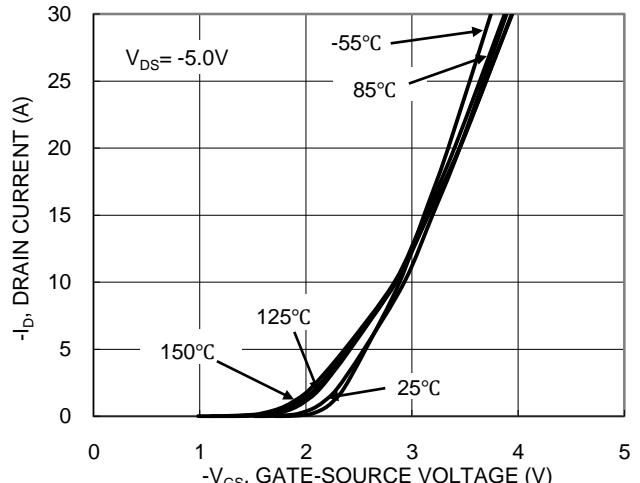


Figure 2. Typical Transfer Characteristic

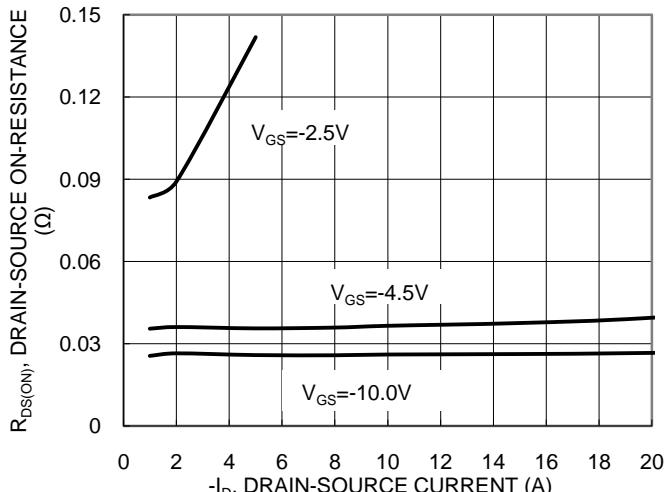


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

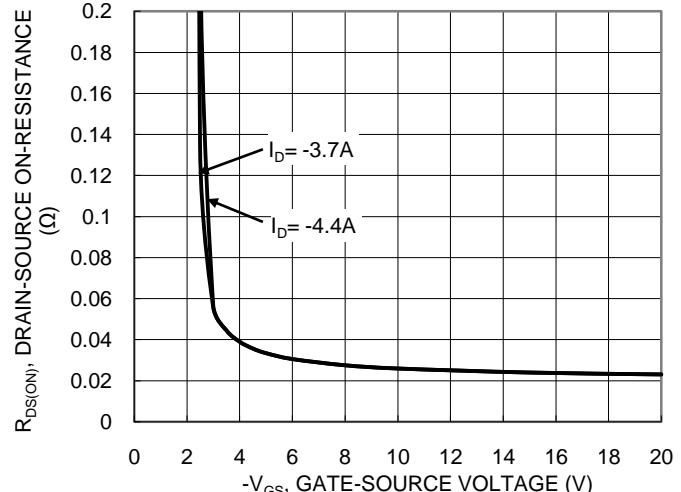


Figure 4. Typical On-Resistance vs. Gate Voltage

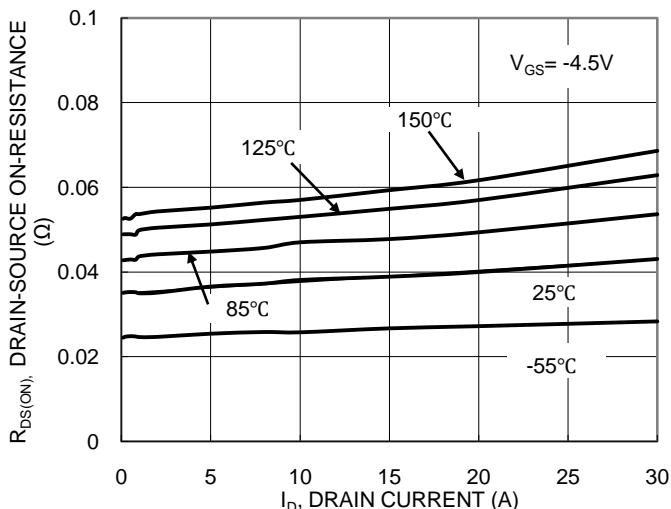


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

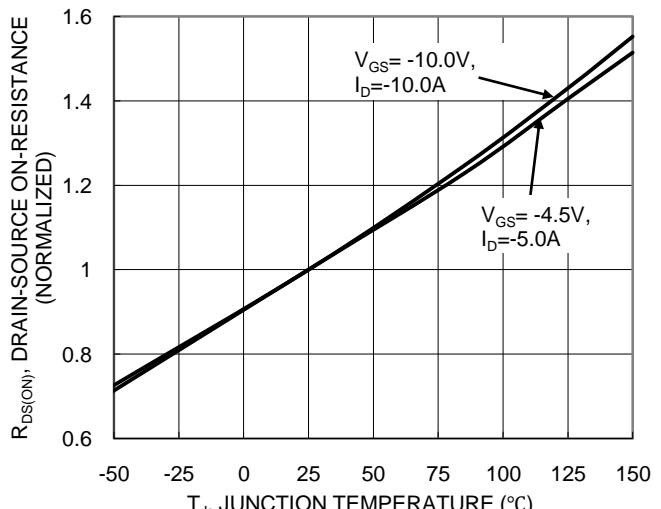
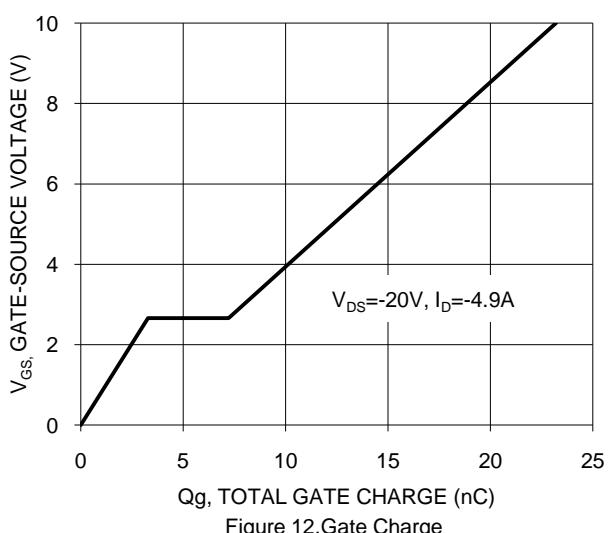
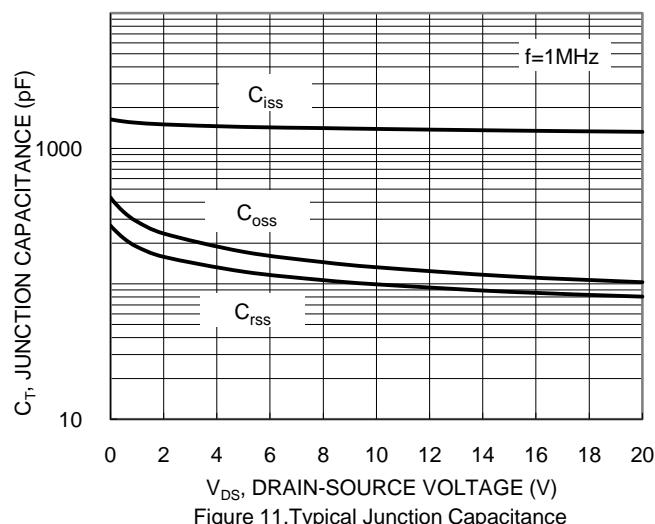
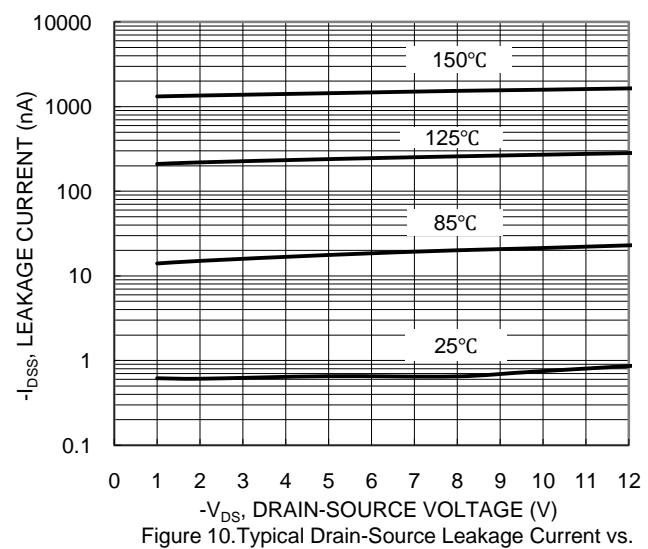
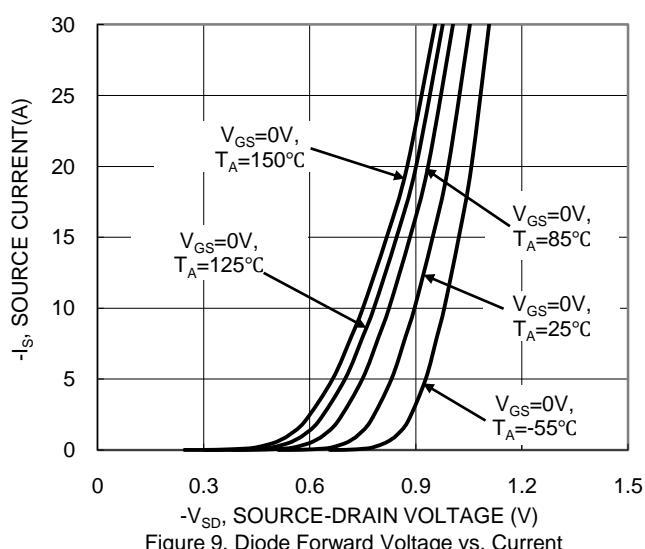
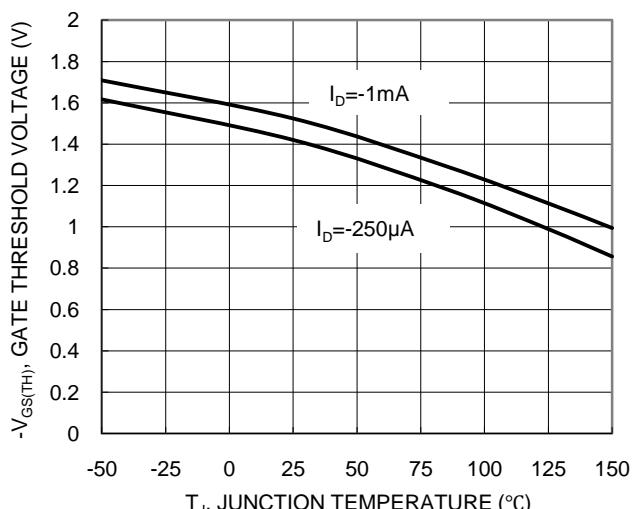
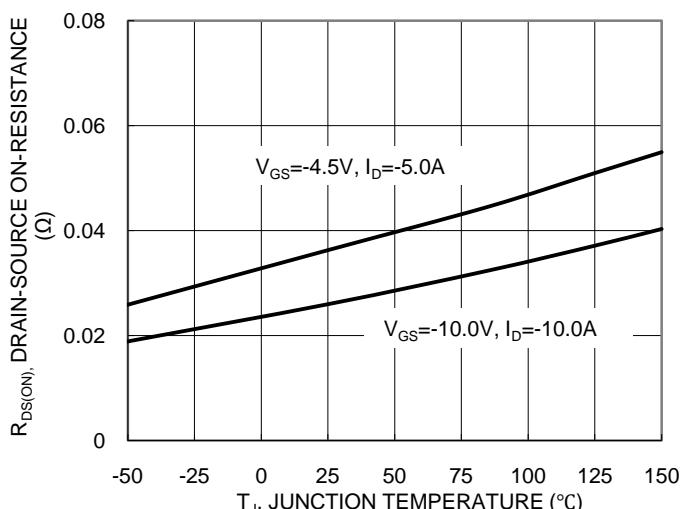


Figure 6. On-Resistance Variation with Temperature



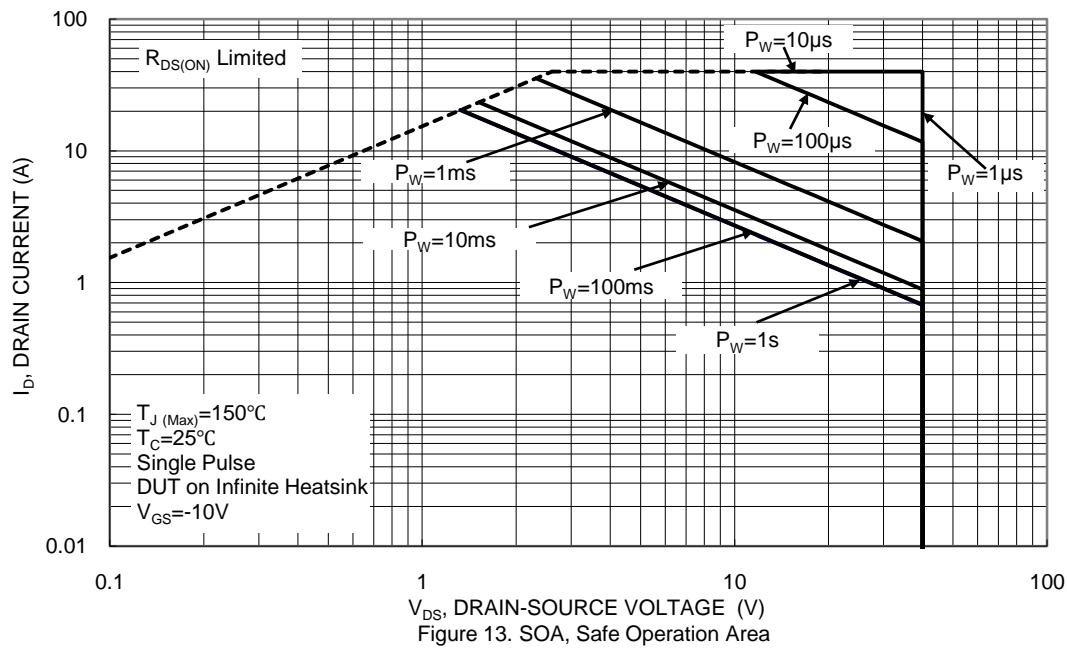


Figure 13. SOA, Safe Operation Area

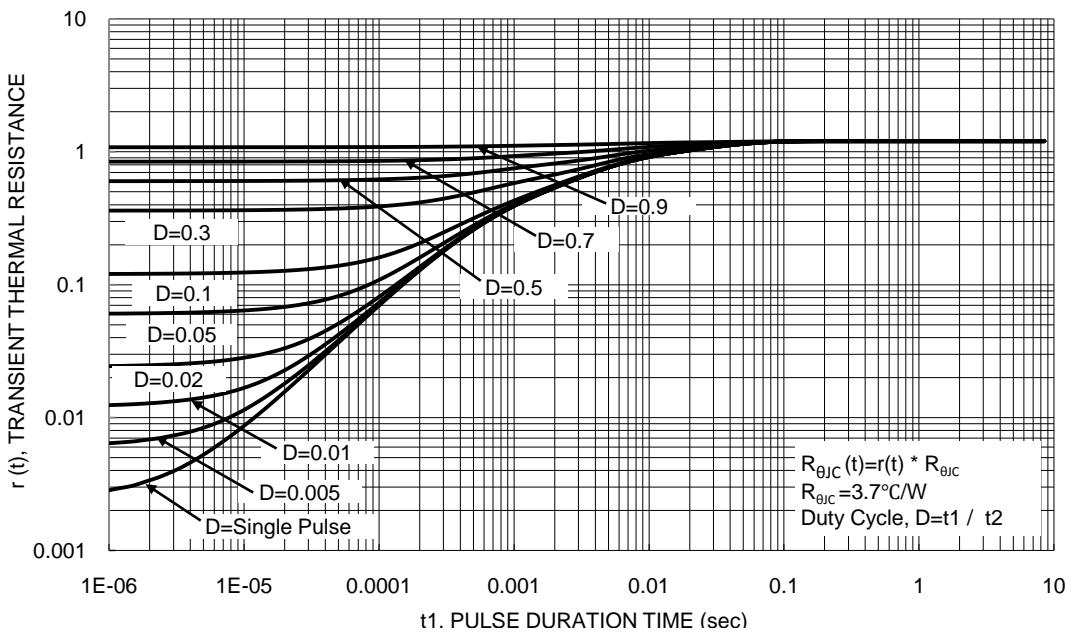
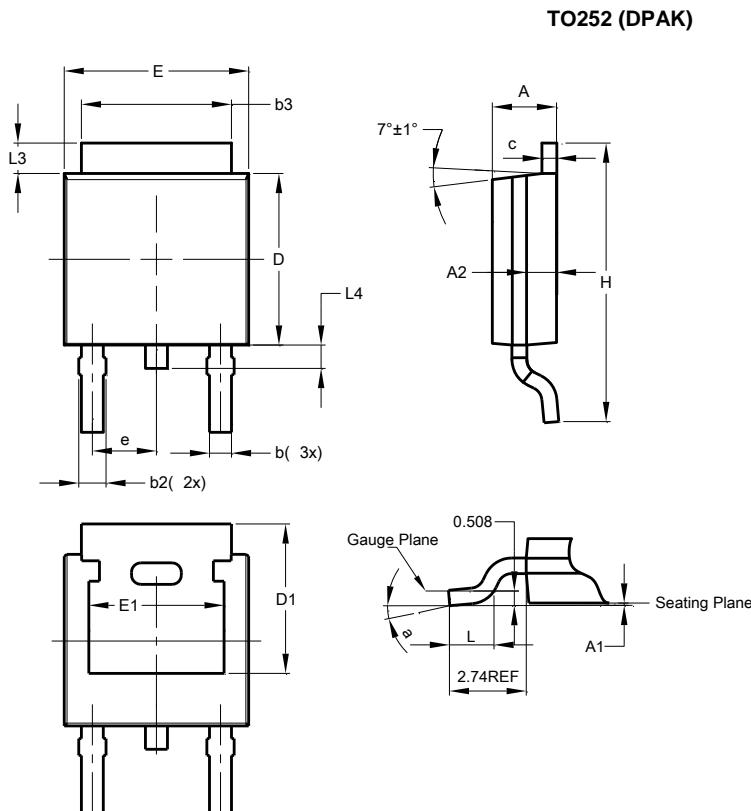


Figure 14. Transient Thermal Resistance

## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

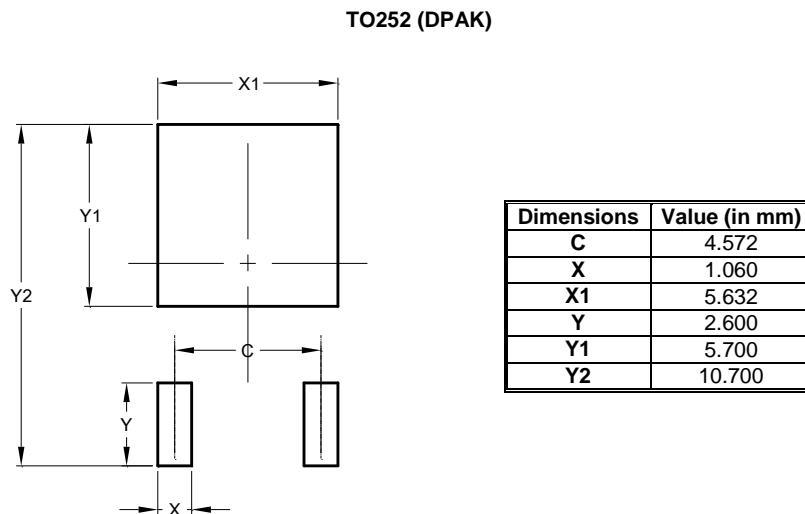


TO252 (DPAK)			
Dim	Min	Max	Typ
<b>A</b>	2.19	2.39	2.29
<b>A1</b>	0.00	0.13	0.08
<b>A2</b>	0.97	1.17	1.07
<b>b</b>	0.64	0.88	0.783
<b>b2</b>	0.76	1.14	0.95
<b>b3</b>	5.21	5.46	5.33
<b>c</b>	0.45	0.58	0.531
<b>D</b>	6.00	6.20	6.10
<b>D1</b>	5.21	-	-
<b>e</b>	-	-	2.286
<b>E</b>	6.45	6.70	6.58
<b>E1</b>	4.32	-	-
<b>H</b>	9.40	10.41	9.91
<b>L</b>	1.40	1.78	1.59
<b>L3</b>	0.88	1.27	1.08
<b>L4</b>	0.64	1.02	0.83
<b>a</b>	0°	10°	-

All Dimensions in mm

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.



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